

# Capacitive Behavior of Manganese Dioxide/Stainless Steel Electrodes at Different Deposition Currents

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**Abstract** Amorphous manganese dioxide thin films were prepared by galvanostatic cathodic deposition at current densities of 0.5-1 mA/cm<sup>2</sup> on etched stainless-steel substrate from 20 mM KMnO<sub>4</sub> solution. The structure of the deposited oxides was investigated using X-ray diffraction analysis. The capacitive behavior of the manganese dioxide electrodes was characterized by cyclic voltammetry and electrochemical impedance spectroscopy in 0.5 M Na<sub>2</sub>SO<sub>4</sub> electrolyte. The capacitive performance was found to increase with the increase in the deposition current density. The electrode deposited at current density of 1 mA/cm<sup>2</sup> showed specific capacitance of 174 F/g at a scan rate of 10 mV/s, equivalent series resistance of 3.53 Ω, and charge transfer resistance of 1.39 Ω. The improvement in the capacitive behavior of the electrode with the increase in the deposition current density was attributed to the increase in the electronic properties of the deposited oxides.

**Keywords** Manganese Dioxide, Supercapacitor, Energy Density, Electrodeposition

## 1. Introduction

Energy storage devices have become more demanded due to the fast growing market of portable electronic devices and hybrid electric vehicles (HEVs)[1]. Supercapacitors, also known as electrochemical capacitors or ultracapacitors, are an energy storage devices capable of storing charges in the electrode/electrolyte interface, have received much attention due to their unique properties, such as pulse supply of high power, longer cycle life and higher energy density[2]. However, the energy density of supercapacitors (< 10 Wh/kg) is lower than that of batteries (> 100 Wh/kg) but their power is significantly higher with lifetime longer[3]. On the basis of the energy storage mechanism, supercapacitors can be classified into two categories[4,5], namely the electrical double-layer capacitor (EDLC) and the pseudocapacitor. EDLCs store charge electrostatically through the charge accumulation at the electrode/electrolyte interface, therefore strongly depending on the surface area of the electrode accessible to the electrolyte. Pseudocapacitors store charge Faradaically through the transfer of charge between electrode and electrolyte. There are two electrode materials that are used to store charge in pseudocapacitors, conducting polymers and metal oxides[3, 6,7]. The latter is of interest

in our work.

Because of their high conductivity, metal oxides have also been explored as a possible electrode material for pseudocapacitors[8-12]. The most of relevant research concerns ruthenium oxide. This is because other metal oxides have yet to obtain comparable capacitances. A very high specific capacitance of up to 750 F/g was reported for RuO<sub>2</sub> prepared at relatively low temperatures[2]. The capacitance of ruthenium oxide is achieved through the insertion and removal, or intercalation, of protons into its amorphous structure. Furthermore, the equivalent series resistance (ESR) of hydrous ruthenium oxide is lower than that of other electrode materials. As a result, ruthenium oxide pseudocapacitors may be able to achieve higher energy and power densities than similar EDLCs and conducting polymer pseudocapacitors.

However, the high cost of this noble metal material limits its further commercial application. Hence, much effort has been aimed at searching for alternative inexpensive electrode materials with good capacitive characteristics, e.g., transition metal oxides, such as MnOx, NiOx, CoOx[2], etc. Thus, a major area of research is to utilize cheap metal oxide and/or the development of fabrication methods to reduce the cost of ruthenium oxide, without reducing the performance[8,9]. MnOx has been considered as a promising electrode material for electrochemical capacitors because of its low cost and excellent capacitive performance in the aqueous electrolytes.

Manganese dioxide is generally produced by anodic deposition at a high current density onto metallic conductive

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substrate using acidified  $\text{MnSO}_4$  solution. However, this method usually leads to the dissolution of the conductive substrate and/or build up an insulating oxide layer at the interface of the active oxide and substrate, which negatively affect the value of specific capacitance as well as the resistance of developed manganese oxide electrodes. To improve the capacitive behavior and resistance of the deposited manganese dioxide, the present study is undertaken to deposit manganese dioxide thin film onto stainless steel substrate from  $\text{KMnO}_4$  aqueous solution using galvanostatic cathodic deposition technique. Special attention is given to study the effects of deposition cathodic current density on the structure properties as well as capacitive performance of  $\text{MnO}_2$  thin film.

## 2. Experimental

Stainless-steel (SS) sheet of grade 316 LN, thickness 0.25 mm and surface area of 6 mm  $\times$  15 mm was used as substrate material for the electrodeposition. The substrate was first etched in a mixture of hydrofluoric acid 40 %: nitric acid 69 %: distilled water with ratio 1:1:1 for 1 hour, then washed and dried in air.

$\text{MnO}_2$  thin films were galvanostatically deposited from 20 mM  $\text{KMnO}_4$  solution at a cathodic current density of 0.5, 0.75, and 1 mA/cm<sup>2</sup> onto SS substrate for 0.5 hour. The weight of the deposited manganese dioxide film was measured by means of a Sartorius micro-balance (Model BP211D). The structure was characterized by means of X-ray diffractometer (Shimadzu, XRD-7000) using  $\text{Cu K}\alpha$  radiation.

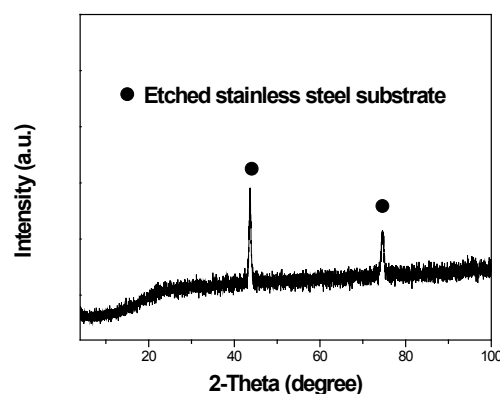
All electrochemical measurements were performed at  $30 \pm 1.0^\circ\text{C}$  using two compartment three electrodes electrochemical cell with platinum foil as an auxiliary electrode and a saturated  $\text{Ag}/\text{AgCl}$  reference electrode. The electrochemical impedance investigations and the cyclic voltammtery (CV) polarisation measurements were carried out in 0.5 M  $\text{Na}_2\text{SO}_4$  electrolyte using VersaSTAT4 potentostat/galvanostat. The CV measurements were carried out at potential ranges of 0–0.9 V vs.  $\text{Ag}/\text{AgCl}$  (sat.) at scan rates of 10–100 mV/s. The excitation amplitude for impedance measurements was 10 mV root mean square in a frequency domain of  $10^{-1}$  to  $10^5$  Hz.

## 3. Results and Discussion

### 3.1. Structure

Figure 1 shows typical X-ray diffraction pattern of  $\text{MnO}_2$  film galvanostatically deposited onto etched SS substrate at 1 mA/cm<sup>2</sup>. The XRD pattern shows sharp peaks corresponding to crystalline stainless steel substrate. No reflection peaks typical to the formation of crystalline or nanocrystalline  $\text{MnO}_2$ , indicating to the formation of amorphous  $\text{MnO}_2$  film. It's worth mentioning that the amorphous phase of the oxide material is generally necessary to have an electrode with

large surface area for supercapacitor applications[13]. Meanwhile, XRD results revealed that the value of deposition current density has insignificant effect on the recorded XRD patterns of the deposited films.

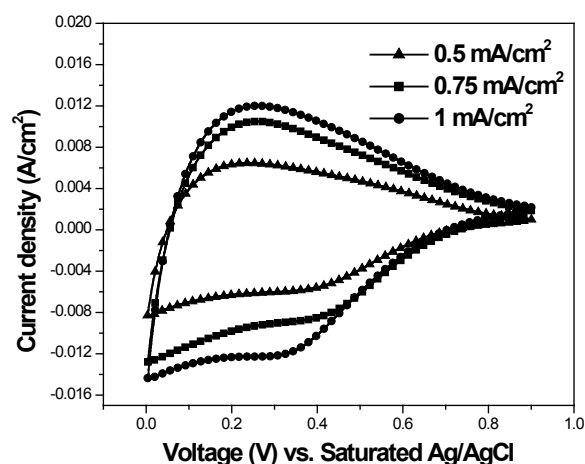


**Figure 1.** XRD pattern for  $\text{MnO}_2$  film galvanostatically deposited at 1 mA/cm<sup>2</sup> on etched SS substrate

### 3.2. Supercapacitive Behavior

#### 3.2.1. Cyclic Voltammtery

Figure 2 shows the CV curves in 0.5 M  $\text{Na}_2\text{SO}_4$  electrolyte for  $\text{MnO}_2$  films obtained at different deposition current densities.



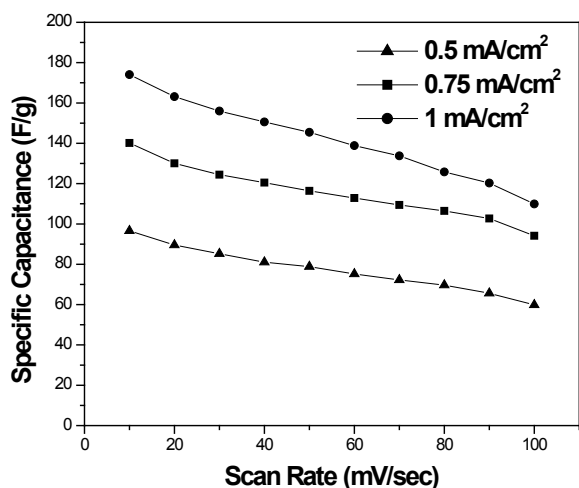
**Figure 2.** Cyclic voltammtery curves of  $\text{MnO}_2$  films measured in 0.5 M  $\text{Na}_2\text{SO}_4$  solution at a scan rate of 100 mV/s as a function of deposition current density

It's clearly seen that all the curves are near-rectangular in shape and show symmetrical anodic and cathodic halves which indicate ideal capacitive behavior of the deposited manganese dioxide films. In addition, the capacitive current density tends to increase with the increase in the deposition current density.

For estimating the specific capacitance (SC) of the deposited oxide films, the amount of capacitive charge (Q) was obtained using half the integrated area of the CV curve presented in Fig. 2, and then the SC was calculated from dividing the capacitive charge by the film mass (m) and the width of the potential window ( $\Delta V$ ) using equation (1).

$$SC = \frac{Q}{m \cdot \Delta V} \quad (1)$$

Figure 3 summarizes the dependence of the specific capacitance on the scan rate of CV measurement for MnO<sub>2</sub> films deposited at different deposition current densities. In general, the specific capacitance decreases as the scan rate increases. This behavior can be attributed to the high probability of exposing both inner and outer surface of the deposited oxide to the ions with the decrease in the scan rate[14]. Meanwhile, the maximum values of the specific capacitance at current densities of 1, 0.75, and 0.5 mA/cm<sup>2</sup> using a scan rate of 10 mV/s are 174, 140, and 97 F/g, respectively.



**Figure 3.** Dependence of the specific capacitance on the scan rate of CV measurement for MnO<sub>2</sub> films deposited at different deposition current densities

### 3.2.2. Electrochemical Impedance Spectroscopy

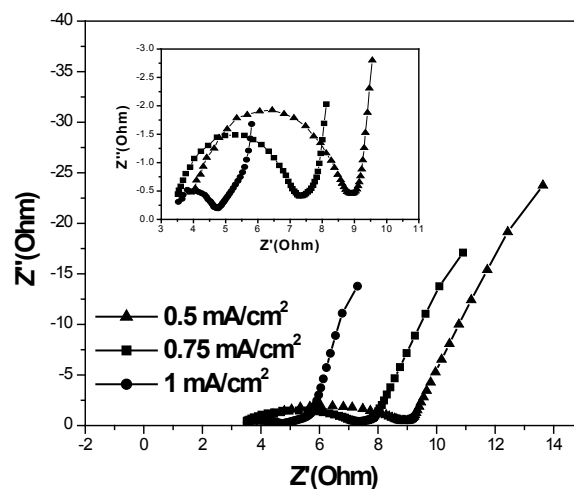
In general, the power output capability of electrochemical supercapacitor depends strongly on not only the rates of ionic mass transport[15] but also the ESR[16]. The ESR is the sum of two major parts, an electronic resistance and an ionic one. Electrochemical impedance spectroscopy has been widely used to study the redox (charging/discharging) processes of electrode materials and to evaluate their electronic and ionic conductivities.

Figure 4 shows the measured Nyquist plots in 0.5 M Na<sub>2</sub>SO<sub>4</sub> electrolyte for MnO<sub>2</sub>/SS electrodes prepared under the different deposition current densities. The inset of Fig. 4 represents the high frequency region of the recorded full impedance plots.

As it can be seen in Fig. 4, two well-separated patterns are observed: an arc is obtained at frequencies high enough, which is related to interfacial processes; the low-frequency region of such plots indicated a capacitive behavior related to the film charging mechanism.

The initial non-zero intersect with the real impedance axis at the beginning of the semicircle indicates the typical ESR value of all system[14,17]. The estimated ESR values for the deposited oxide films at deposited

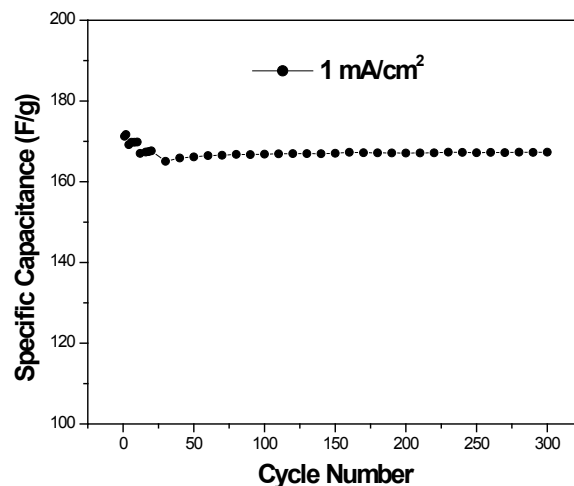
current densities of 1, 0.75, and 0.5 mA/cm<sup>2</sup> are 3.53, 3.54, and 3.91 Ω, respectively. The results indicate that the variation in the ESR value with the deposition current density is insignificant.



**Figure 4.** Nyquist plots of MnO<sub>2</sub>/SS electrodes prepared under different deposition current densities

On the other hand, all spectra showed a clear semi-circle at the high frequency region, which corresponds to the charge transfer resistance ( $R_{ct}$ )[3]. The magnitude of the  $R_{ct}$  can be derived from diameter of the semi-circle[18]. The estimated  $R_{ct}$  values of the MnO<sub>2</sub> films deposited at 1, 0.75, and 0.5 mA/cm<sup>2</sup> are 1.39, 4, and 5.28 Ω, respectively. The decrease in the  $R_{ct}$  value with increase in the deposition current density indicates that the enhancement in pseudocapacitive characteristics is mainly due to an improvement in the electronic properties of the deposited oxide by the deposition at high current density, such as 1 mA/cm<sup>2</sup>.

Meanwhile, the comparison of imaginary impedance ( $Z''$ ) data at the same frequencies for all the deposited films confirms that the capacitive behavior of the deposited film increases with the increase in the deposition current density. This fact is in a good agreement with the SC data presented in Fig. 3.



**Figure 5.** Life-cycle data of MnO<sub>2</sub>/SS electrode at discharge current density 5.5 mA/cm<sup>2</sup>

### 3.2.3. Cyclic Stability using Galvanostatic Charge–Discharge

The life-cycle test of the deposited  $\text{MnO}_2$  film at  $1 \text{ mA/cm}^2$  was performed at discharge current density  $5.5 \text{ mA/cm}^2$  and the result is presented in Fig. 5.

As it can be seen, there is a little decrease in the value of specific capacitance in the first 10 cycles and then the specific capacitance value remained almost constant. A decrease of about 2.3 % in the initial specific capacitance was observed after 300 cycles. This decrease in the specific capacitance is very less compared to the value reported in the literature[19] and indicates the high stability of the deposited film.

## 4. Conclusions

In an attempt to develop a novel electrode with low cost, high capacitive performance and long cyclic stability, amorphous manganese dioxide thin films were galvanostatically deposited onto etched SS electrodes from  $\text{KMnO}_4$  solution at different cathodic current densities in range of  $0.5\text{-}1 \text{ mA/cm}^2$ . The capacitive performance of the films was found to increase with the increase in deposition current density. The  $\text{MnO}_2$  film deposited at current density of  $1 \text{ mA/cm}^2$  has the highest SC of  $174 \text{ F/g}$  at a scan rate of  $10 \text{ mV/s}$  and the smallest charge transfer resistance of  $1.39 \Omega$ . The excellent capacitive performance suggests that the amorphous  $\text{MnO}_2$  films obtained by cathodic deposition from  $\text{KMnO}_4$  solution has the potential to be used as an electrode material for high performance supercapacitors.

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## REFERENCES

- [1] L.L. Zhang, W. Tianxin, W. Wenjuan, and X.S. Zhao, "Manganese oxide–carbon composite as supercapacitor electrode materials", *Microporous and Mesoporous Materials*, Vol. 123, pp. 260–267, 2009.
- [2] D. Zhao, Z. Yang, E.S. Kong, C. Xu, and Y. Zhang, "Carbon nanotube arrays supported manganese oxide and its application in electrochemical capacitors", *J. Solid State Electrochem.* DOI 10.1007/s10008-010-1182-x.
- [3] B.E. Conway, *Electrochemical Supercapacitors: Scientific Fundamentals and Technological Applications*, Kluwer Academic/Plenum, New York, 1999.
- [4] M. Winter, and R.J. Brodd, "What Are Batteries, Fuel Cells, and Supercapacitors", *Chem. Rev.*, Vol. 104, pp. 4245-4270, 2004.
- [5] A.G. Pandolfo, and A.F. Hollenkamp, "Carbon properties and their role in supercapacitors", *J. Power Sources*, Vol. 157, pp. 11-27, 2006.
- [6] B.E. Conway, "Transition from "supercapacitor" to "battery" behavior in electrochemical energy storage", *Journal of the Electrochemical Society*, Vol. 138, No. 6, pp. 1539-1548, 1991.
- [7] B.E. Conway, V. Birss, and J. Wojtowicz, "The role and utilization of pseudocapacitance for energy storage by supercapacitors", *Journal of Power Sources*, Vol. 66, No. 1-2, pp. 1-14, 1997.
- [8] A. Burke, "Ultracapacitors: why, how, and where is the technology", *Journal of Power Sources*, Vol. 91, No. 1, pp. 3750, 2000.
- [9] R. Kotz, and M. Carlen, "Principles and applications of electrochemical capacitors", *Electrochimica Acta*, Vol. 45, No. 15-16, pp. 2483-2498, 2000.
- [10] I.H. Kim, and K.B. Kim, "Ruthenium oxide thin film electrodes for supercapacitors", *Electrochemical and Solid State Letters*, Vol. 4, No. 5, pp. A62-A64, 2001.
- [11] J.P. Zheng, and T.R. Jow, "A New Charge Storage Mechanism for Electrochemical Capacitors", *Journal of the Electrochemical Society*, Vol. 142, No. 1, pp. L6-L8, 1995.
- [12] J.P. Zheng, P.J. Cygan, and T.R. Jow, "Hydrous Ruthenium Oxide as an Electrode Material for Electrochemical Capacitors", *Journal of the Electrochemical Society*, Vol. 142, No 8, pp. 2699-2703, 1995.
- [13] D.P. Dubal, D.S. Dhawale, T.P. Gujar, and C.D. Lokhande, "Effect of different modes of electrodeposition on supercapacitive properties of  $\text{MnO}_2$  thin films", *Applied Surface Science*, Vol. 257: pp. 3378–3382, 2011.
- [14] Y. Zhang, G. Li, Y. Lv, L. Wang, A. Zhang, Y. Song, and B. Huang, "Electrochemical investigation of  $\text{MnO}_2$  electrode material for supercapacitors", *International Journal of Hydrogen Energy*, Vol. 36, pp. I1760-I1766, 2011.
- [15] A. Izadi-Najafabadi, T.H. Tand, and J.D. Madden, "Towards high power polypyrrole/carbon capacitors", *Synth Met.*, Vol. 152, pp. 129–132, 2005.
- [16] A. Celzard, F. Collas J.F. Mareche, G. Furdin, and I. Rey, "Porous electrodes-based double-layer supercapacitors: pore structure versus series resistance", *J Power Sources*, Vol. 108, pp. 153–162, 2002.
- [17] Q. Lu, and Y. Zhou, "Synthesis of mesoporous polythiophene/ $\text{MnO}_2$  nanocomposite and its enhanced pseudocapacitive properties", *J. Power Sources*, Vol. 196, pp. 4088-4094, 2011.
- [18] T. Tuken, B. Yazici, and M. Erbil, "A new multilayer coating for mild steel protection", *Prog. Org. Coat.*, Vol. 50, pp. 115–122, 2004.
- [19] K.R. Prasad, and N. Miura, "Potentiodynamically deposited nanostructured manganese dioxide as electrode material for electrochemical redox supercapacitors". *Journal of Power Sources*, Vol. 135, pp. 354–360, 2004.